Supporting Information

Highly Efficient Photoelectrochemical Hydrogen Generation Reaction Using Tungsten Phosphosulfide Nanosheets

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EXPERIMENTAL SECTION

Photoelectrochemical measurements

Photoelectrochemical measurement was performed using a typical three electrochemical cell setup (760D, CH Instruments). The prepared WS_{2-x}P_x@Si MPs were used as working photocathode electrode, connected with copper wire through silver paste, and dried at 60 °C for 2 h. Epoxy paste was applied on the silver paste to prevent further PEC reaction. Linear sweep voltammetry (LSV) profiles were determined at a scan rate of 20 mV/s by using 0.5 M H₂SO₄ (pH=0.3) supporting electrolyte solution to evaluate the solar-driven PEC hydrogen evolution reaction. Silver chloride (Ag/AgCl; sat. KCl) and platinum (Pt) wire were used as reference and counter electrodes, respectively. Xenon lamp (500 W; LSH-X500) was used as light source and equipped with AM 1.5 filter (110 mWcm⁻²) for PEC measurement. The system was enclosed within the water circulation system to control the temperature of the cell at 25 °C. Chronoamperometry techniques were used to perform the stability test of the photocathode at 0 V vs. RHE.

Material characterization

Scanning electron microscopy (SEM; JSM-6700F-JEOL) analysis was conducted to investigate the morphology of the WS_{2-x}P_x@Si MPs and WS₂@Si MPs nanomaterials. Energy-dispersive X-ray spectroscopy (EDX) mapping studies were also performed through SEM (JSM-6700F-JEOL). The crystallinity of the samples was investigated by X-ray diffraction analysis using a Bruker D2 PHASER XRD analyzer (Cu K α). Raman measurement was carried out using a Thermo DXR microscope (532 nm laser light) for WS₂. xP_x@Si MPs and WS₂@Si MPs nanomaterials. X-ray absorption near the edge structure (XANES) measurement was carried out in 01C1 and 17C1 beamlines of the National Synchrotron Radiation Research Center (NSRRC) in Hsinchu City, Taiwan.



Figure S1. Top-view SEM images of the (a) bare Si MPs, (b) $WS_2@Si$ MPs, (c) $WS_{0.60}P_{1.40}@Si$ MPs, and (d) $WS_{0.40}P_{1.60}@Si$ MPs photoelectrodes.



Figure S2. (a) SEM image and elemental mapping images of (b) W and (c) S of the WS_2 sample.



Figure S3. (a) SEM image and elemental mapping images of (b) W, (c) S, and (d) P of the $WS_{0.40}P_{1.60}$ samples.



Figure S4. EXAFS (W L₃-edge) spectra of the WS₂, WS_{0.60}P_{1.40}, and WS_{0.40}P_{1.60} samples.



Figure S5. J–V curves of $W_{1.0}P_{1.0}$ (2) Si MPs photocathode at current density at 0 V vs. RHE.



Figure S6. Tafel slopes of WS₂@Si MPs, WS_{0.60}P_{1.40}@Si MPs, and WS_{0.40} P_{1.60}@Si MPs electrodes.



Figure S7. Nyquist plots of $WS_2@Si MPs$, $WS_{0.60}P_{1.40}@Si MPs$ and $WS_{0.40}P_{1.60}@Si MPs$ electrodes.